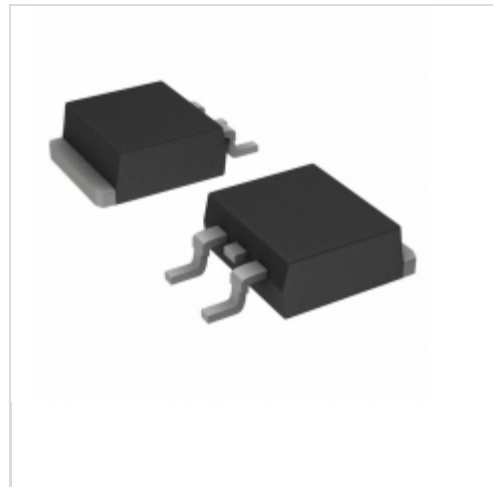


BYWB29-50-E3/45

Vishay / Semiconductor - Diodes Division

DIODE GEN PURP 50V 8A TO263AB

Lead free / RoHS Compliant

Discrete Semiconductor Products

[1.BYWB29-50-E3/45.pdf](#)
[2.BYWB29-50-E3/45.pdf](#)
Out Stock
0 pcs

Minimum:1

Multiples:100

Manufacturer lead time 10 weeks

We can supply BYWB29-50-E3/45, use the request quote form to request BYWB29-50-E3/45 price and lead time. Zeano is a professional electronic components distributor. With 3+ Million line items of available electronic components can ship in short lead-time, over 250 thousand part numbers of electronic components in stock for immediately delivery, which may include part number BYWB29-50-E3/45. The price and lead time for BYWB29-50-E3/45 depending on the quantity required and warehouse location. Contact us and our sales representative will provide you price. We look forward to work with you.

Shopping Process
1
Confirm the product
2
submit the order
3
payment
4
wait for delivery
5
receive the goods
Specifications

Voltage - Forward (Vf) (Max) @ If:	1.3V @ 20A
Voltage - DC Reverse (Vr) (Max):	50V
Supplier Device Package:	TO-263AB
Speed:	Fast Recovery = 200mA (Io)
Series:	-
Reverse Recovery Time (trr):	25ns
Packaging:	Tube
Package / Case:	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Operating Temperature - Junction:	-65°C ~ 150°C
Mounting Type:	Surface Mount
Diode Type:	Standard
Current - Reverse Leakage @ Vr:	10µA @ 50V
Current - Average Rectified (Io):	8A
Capacitance @ Vr, F:	-

Related products

BYWB29-50HE3/45

DIODE GEN PURP 50V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


BYWB29-200HE3/45

DIODE GEN PURP 200V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


BYWB29-200-E3/81

DIODE GEN PURP 200V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


BYWB29-50HE3/81

DIODE GEN PURP 50V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


BYWB29-200-E3/45

DIODE GEN PURP 200V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


BYWB29-50-E3/81

DIODE GEN PURP 50V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


BYWB29-200
[PH/ST](#)

RFQ


BYWE29-100-E3/45

DIODE GEN PURP 100V 8A TO220AC

[Vishay Semiconductor Diodes Division](#)

RFQ


BYWB29-200HE3/81

DIODE GEN PURP 200V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


BYWE29-200-E3/45

DIODE GEN PURP 200V 8A TO220AC

[Vishay Semiconductor Diodes Division](#)

RFQ

Guess You May Looking For

SIT1602BC-23-30S-35.840000E

-20 TO 70C, 3225, 50PPM, 3.0V, 3

[SITIME](#)

RFQ


SIT1602BC-71-33S-50.000000E

-20 TO 70C, 2016, 20PPM, 3.3V, 5

[SITIME](#)

RFQ


SIT1602BI-33-28S-19.200000Y

-40 TO 85C, 5032, 50PPM, 2.8V, 1

[SITIME](#)

RFQ


SIT1602BI-33-28N-72.000000T

-40 TO 85C, 5032, 50PPM, 2.8V, 7

[SITIME](#)

RFQ


SIT8008BC-83-33E-58.495000Y

OSC MEMS 58.4950MHZ LVCMOS SMD

[SITIME](#)

RFQ


SIT1602BI-71-28S-66.666660E

-40 TO 85C, 2016, 20PPM, 2.8V, 6

[SITIME](#)

RFQ


SIT1602BC-32-33E-27.000000T

OSC MEMS 27.0000MHZ LVCMOS SMD

[SITIME](#)

RFQ


SIT1602BI-21-28N-35.840000D

-40 TO 85C, 3225, 20PPM, 2.8V, 3

[SITIME](#)

RFQ


SIT1602AI-32-33E-32.768000Y

OSC XO 3.3V 32.768MHZ OE

[SITIME](#)

RFQ


SIT1602BI-81-30N-8.192000Y

-40 TO 85C, 7050, 20PPM, 3.0V, 8

[SITIME](#)

RFQ